

N-Channel NexFET™ Power MOSFETs

Check for Samples: [CSD16409Q3](#)

FEATURES

- Ultra Low Q_g and Q_{gd}
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 3.3mm x 3.3mm Plastic Package

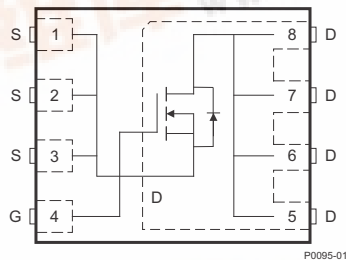
APPLICATIONS

- Point-of-Load Synchronous Buck Converter for Applications in Networking, Telecom and Computing Systems
- Optimized for Control FET Applications

DESCRIPTION

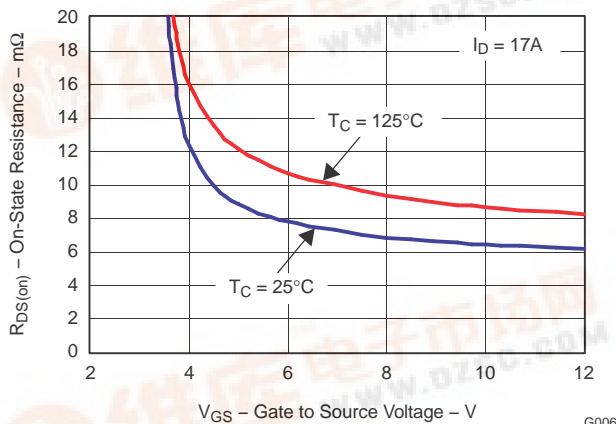
The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.

Top View



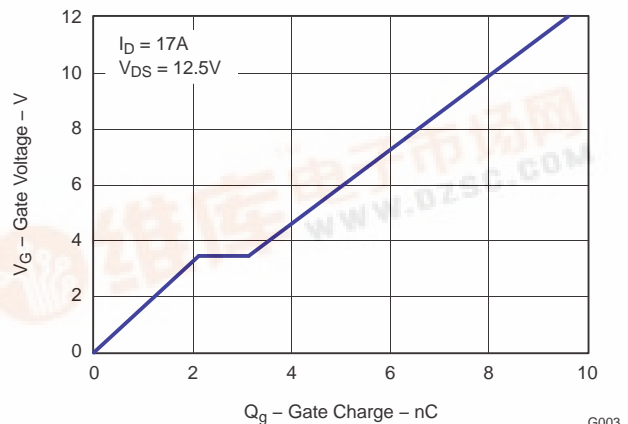
P0095-01

$R_{DS(ON)}$ vs V_{GS}



G006

Gate Charge



G003

PRODUCT SUMMARY

| | | | |
|--------------|-------------------------------|-----------------|--------|
| V_{DS} | Drain to Source Voltage | 25 | V |
| Q_g | Gate Charge Total (4.5V) | 4 | nC |
| Q_{gd} | Gate Charge Gate to Drain | 1 | nC |
| $R_{DS(on)}$ | Drain to Source On Resistance | $V_{GS} = 4.5V$ | 9.5 mΩ |
| | | $V_{GS} = 10V$ | 6.2 mΩ |
| V_{th} | Threshold Voltage | 2 | V |

ORDERING INFORMATION

| Device | Package | Media | Qty | Ship |
|------------|-------------------------------|--------------|------|---------------|
| CSD16409Q3 | SON 3.3 x 3.3 Plastic Package | 13-inch reel | 2500 | Tape and Reel |

ABSOLUTE MAXIMUM RATINGS

| $T_A = 25^\circ\text{C}$ unless otherwise stated | | VALUE | UNIT |
|--|---|------------|------------------|
| V_{DS} | Drain to Source Voltage | 25 | V |
| V_{GS} | Gate to Source Voltage | +16 / -12 | V |
| I_D | Continuous Drain Current, $T_C = 25^\circ\text{C}$ | 60 | A |
| | Continuous Drain Current ⁽¹⁾ | 15 | A |
| I_{DM} | Pulsed Drain Current, $T_A = 25^\circ\text{C}$ ⁽²⁾ | 90 | A |
| P_D | Power Dissipation ⁽¹⁾ | 2.6 | W |
| T_J, T_{STG} | Operating Junction and Storage Temperature Range | -55 to 150 | $^\circ\text{C}$ |
| E_{AS} | Avalanche Energy, single pulse $I_D = 38A, L = 0.1\text{mH}, R_G = 25\Omega$ | 72 | mJ |

(1) $R_{\theta JA} = 47^\circ\text{C/W}$ on 1in^2 Cu (2 oz.) on 0.060" thick FR4 PCB.

(2) Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NexFET is a trademark of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

Copyright © 2009–2010, Texas Instruments Incorporated





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

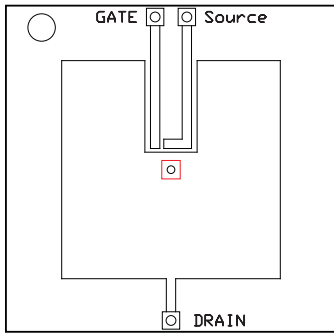
| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------------------------|----------------------------------|---|-----|------|------|------|
| Static Characteristics | | | | | | |
| V _{DSS} | Drain to Source Voltage | V _{GS} = 0V, I _D = 250μA | 25 | | | V |
| I _{DSS} | Drain to Source Leakage Current | V _{GS} = 0V, V _{DS} = 20V | | | 1 | μA |
| I _{GSS} | Gate to Source Leakage Current | V _{DS} = 0V, V _{GS} = +16/-12V | | | 100 | nA |
| V _{GS(th)} | Gate to Source Threshold Voltage | V _{DS} = V _{GS} , I _D = 250μA | 1.7 | 2 | 2.3 | V |
| R _{DS(on)} | Drain to Source On Resistance | V _{GS} = 4.5V, I _D = 17A | | 9.5 | 12.4 | mΩ |
| | | V _{GS} = 10V, I _D = 17A | | 6.2 | 8.2 | mΩ |
| g _{fs} | Transconductance | V _{DS} = 15V, I _D = 17A | | 38 | | S |
| Dynamic Characteristics | | | | | | |
| C _{ISS} | Input Capacitance | V _{GS} = 0V, V _{DS} = 12.5V, f = 1MHz | | 600 | 800 | pF |
| C _{OSS} | Output Capacitance | | | 480 | 635 | pF |
| C _{RSS} | Reverse Transfer Capacitance | | | 40 | 55 | pF |
| R _g | Series Gate Resistance | | | 0.9 | 1.8 | Ω |
| Q _g | Gate Charge Total (4.5V) | V _{DS} = 12.5V, I _D = 17A | | 4 | 5.6 | nC |
| Q _{gd} | Gate Charge Gate to Drain | | | 1 | | nC |
| Q _{gs} | Gate Charge Gate to Source | | | 2.1 | | nC |
| Q _{g(th)} | Gate Charge at V _{th} | | | 1.1 | | nC |
| Q _{OSS} | Output Charge | V _{DS} = 12.9V, V _{GS} = 0V | | 9.1 | | nC |
| t _{d(on)} | Turn On Delay Time | V _{DS} = 12.5V, V _{GS} = 4.5V, I _D = 17A, R _G = 2Ω | | 6.5 | | ns |
| t _r | Rise Time | | | 10.6 | | ns |
| t _{d(off)} | Turn Off Delay Time | | | 6.3 | | ns |
| t _f | Fall Time | | | 3.4 | | ns |
| Diode Characteristics | | | | | | |
| V _{SD} | Diode Forward Voltage | I _S = 17A, V _{GS} = 0V | | 0.85 | 1 | V |
| Q _{rr} | Reverse Recovery Charge | V _{DD} = 12.9V, I _F = 17A, di/dt = 300A/μs | | 13.8 | | nC |
| t _{rr} | Reverse Recovery Time | V _{DD} = 12.9V, I _F = 17A, di/dt = 300A/μs | | 17.5 | | ns |

THERMAL CHARACTERISTICS

(T_A = 25°C unless otherwise stated)

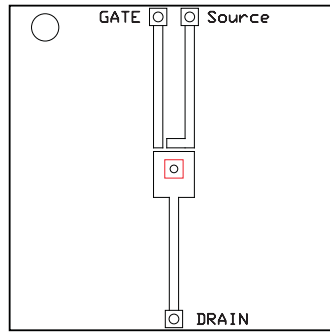
| PARAMETER | | MIN | TYP | MAX | UNIT |
|------------------|---|-----|-----|-----|------|
| R _{θJC} | Thermal Resistance Junction to Case ⁽¹⁾ | | | 3.5 | °C/W |
| R _{θJA} | Thermal Resistance Junction to Ambient ^{(1) (2)} | | | 59 | °C/W |

- (1) R_{θJC} is determined with the device mounted on a 1 inch square 2 oz. Cu pad on a 1.5 × 1.5 in 0.06 inch thick FR4 board. R_{θJC} is specified by design while R_{θJA} is determined by the user's board design.
 (2) Device mounted on FR4 Material with 1 inch² of 2 oz. Cu.



M0161-01

Max $R_{\theta JA} = 59^{\circ}\text{C/W}$
when mounted on 1
 inch^2 of 2 oz. Cu.

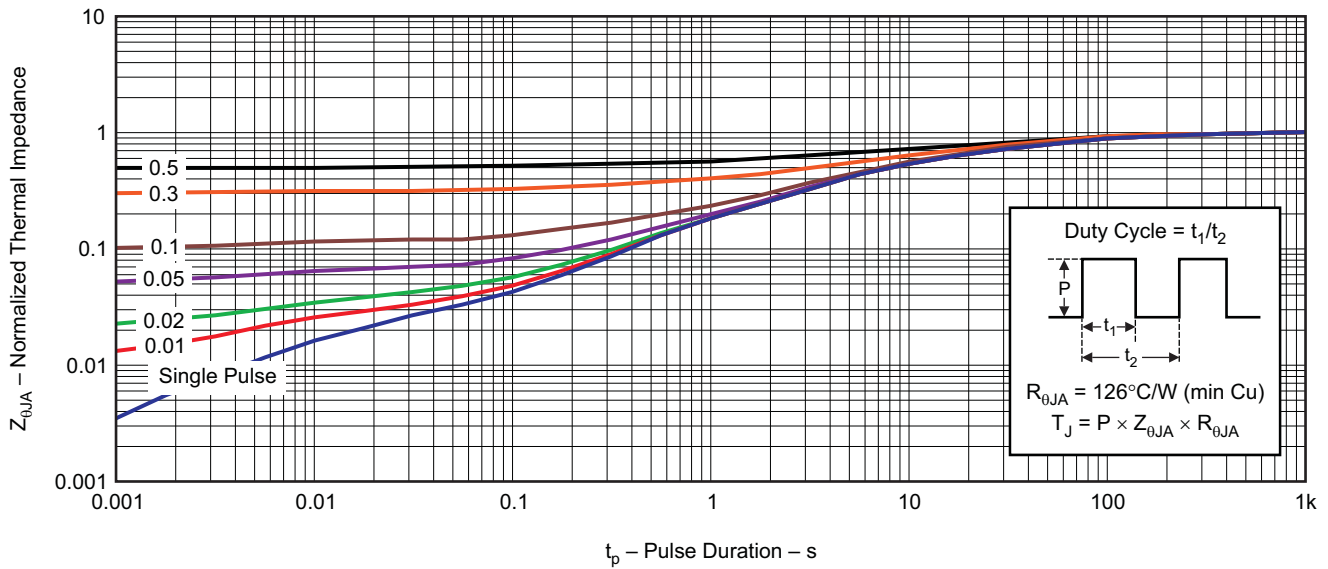


M0161-02

Max $R_{\theta JA} = 157^{\circ}\text{C/W}$
when mounted on
minimum pad area of 2
oz. Cu.

TYPICAL MOSFET CHARACTERISTICS

($T_A = 25^{\circ}\text{C}$ unless otherwise stated)



G012

Figure 1. Transient Thermal Impedance

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

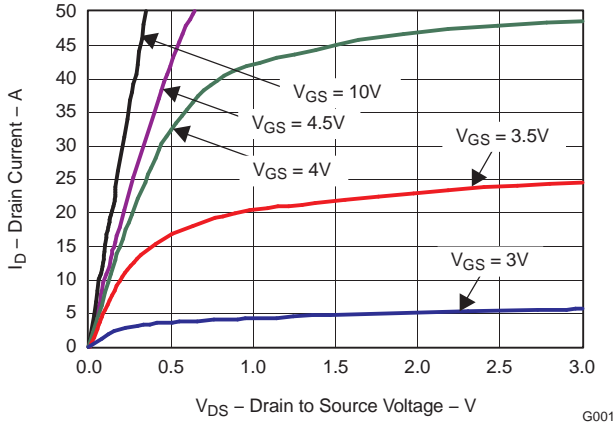


Figure 2. Saturation Characteristics

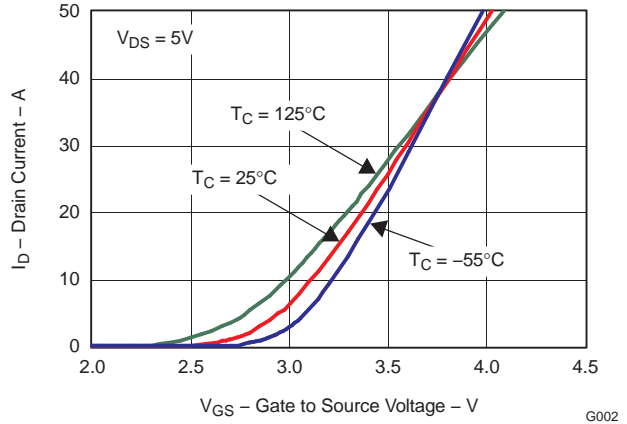


Figure 3. Transfer Characteristics

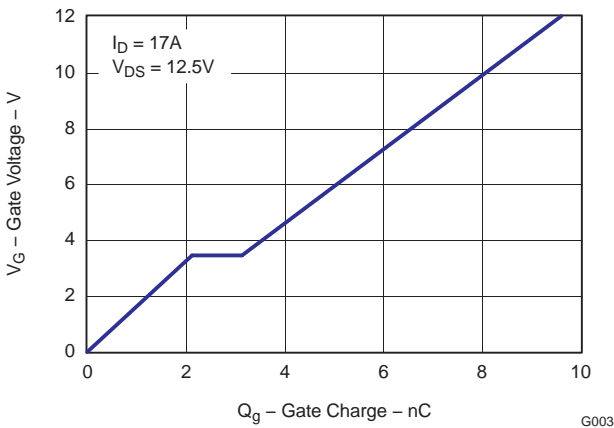


Figure 4. Gate Charge

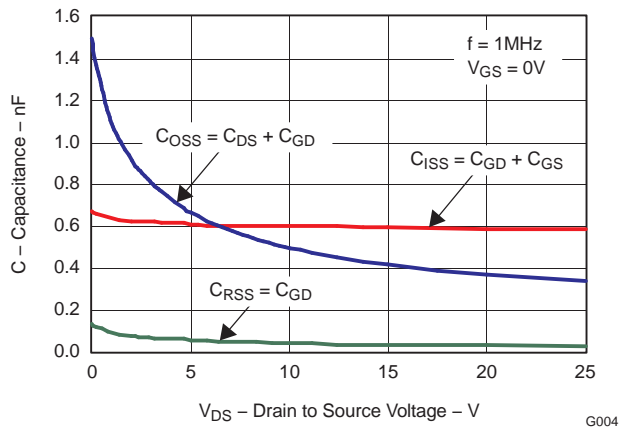


Figure 5. Capacitance

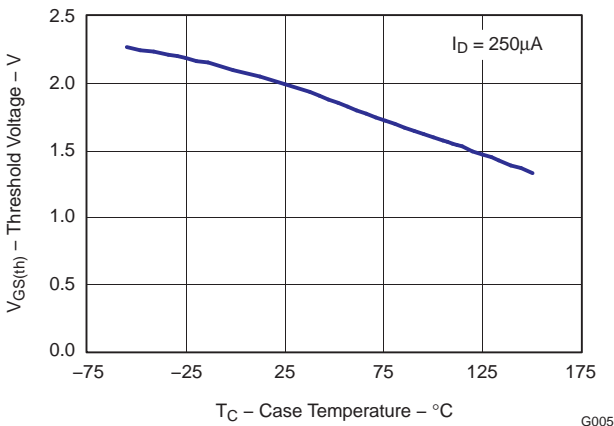


Figure 6. Threshold Voltage vs. Temperature

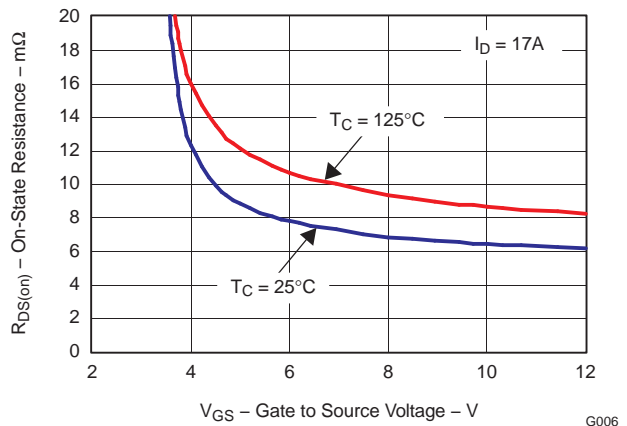


Figure 7. On Resistance vs. Gate Voltage

TYPICAL MOSFET CHARACTERISTICS (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)

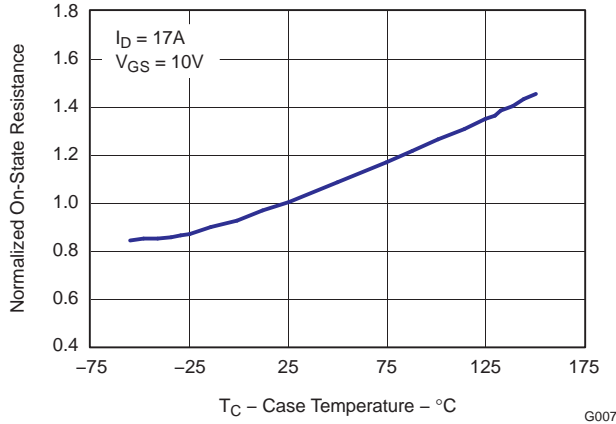


Figure 8. Normalized On Resistance vs. Temperature

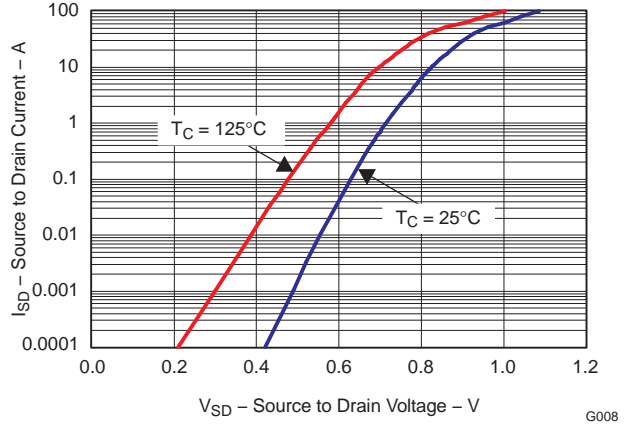


Figure 9. Typical Diode Forward Voltage

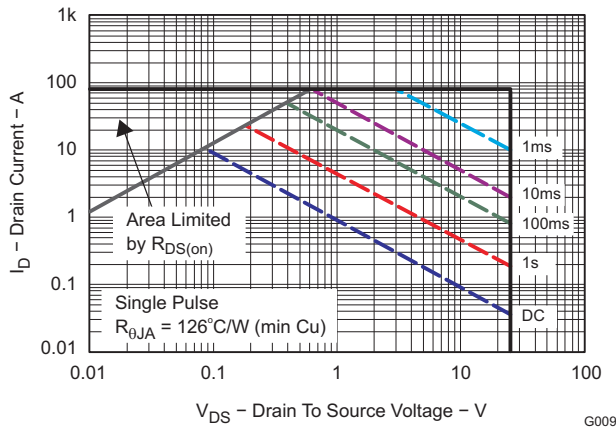


Figure 10. Maximum Safe Operating Area

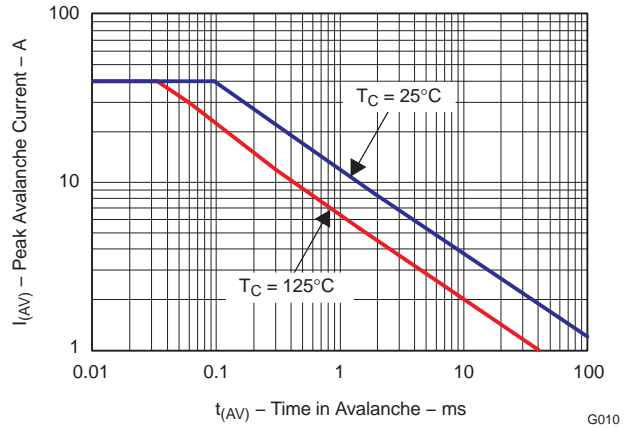


Figure 11. Single Pulse Unclamped Inductive Switching

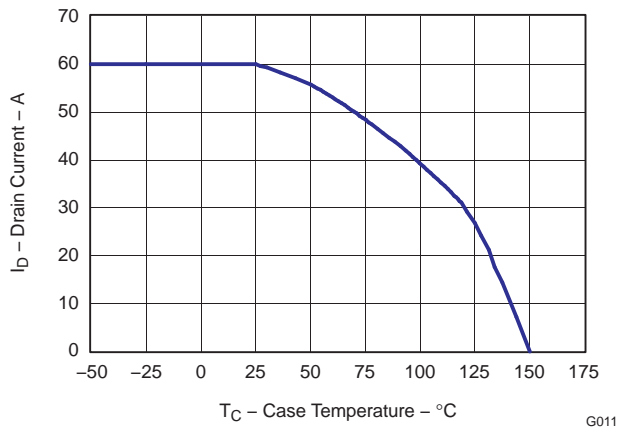
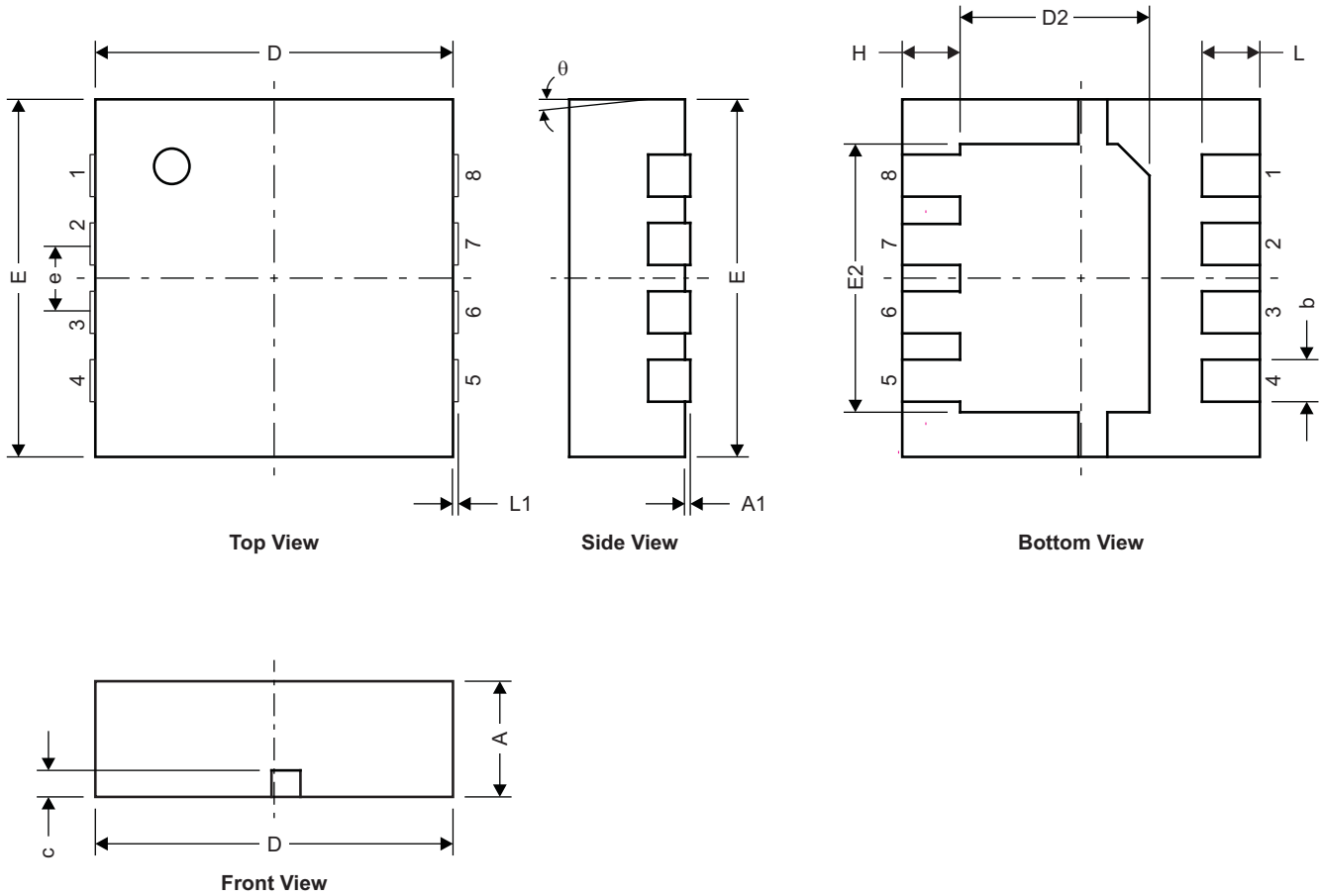


Figure 12. Maximum Drain Current vs. Temperature

MECHANICAL DATA

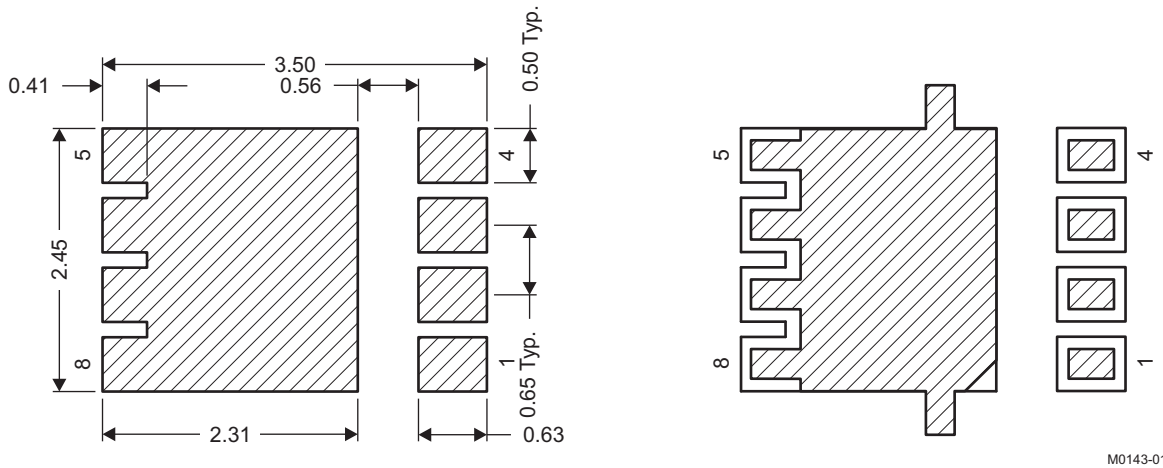
Q3 Package Dimensions



M0142-01

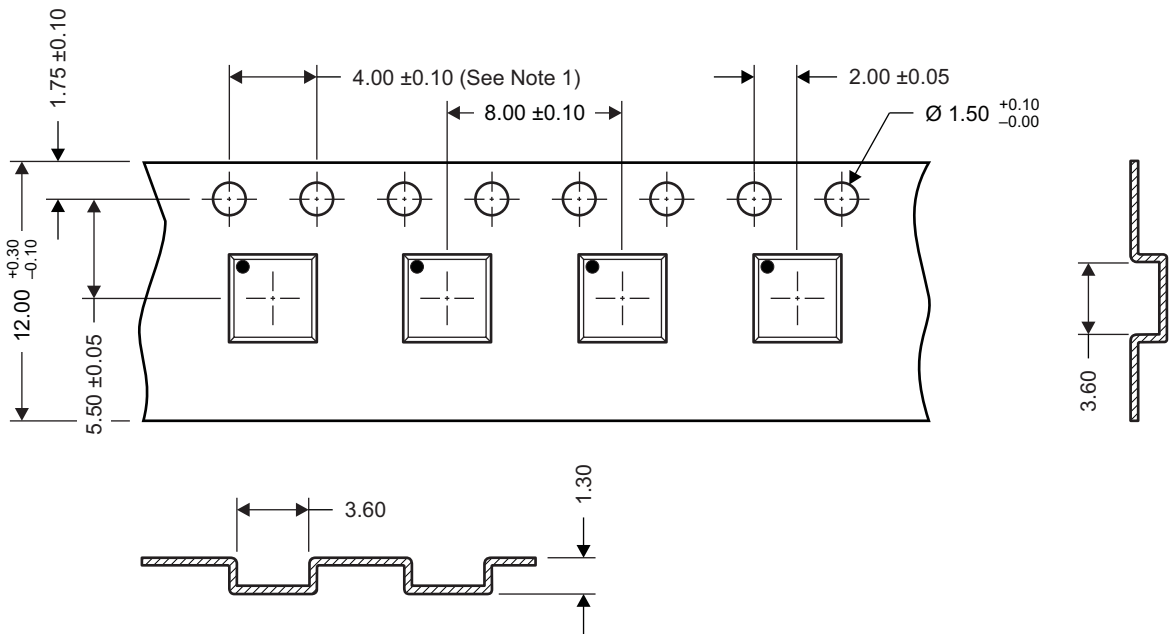
| DIM | MILLIMETERS | | | INCHES | | |
|----------|-------------|-------|-------|--------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 0.950 | 1.000 | 1.100 | 0.037 | 0.039 | 0.043 |
| A1 | 0.000 | 0.000 | 0.050 | 0.000 | 0.000 | 0.002 |
| b | 0.280 | 0.340 | 0.400 | 0.011 | 0.013 | 0.016 |
| c | 0.150 | 0.200 | 0.250 | 0.006 | 0.008 | 0.010 |
| D | 3.200 | 3.300 | 3.400 | 0.126 | 0.130 | 0.134 |
| D1 | - | - | - | - | - | - |
| D2 | 1.650 | 1.750 | 1.800 | 0.065 | 0.069 | 0.071 |
| E | 3.200 | 3.300 | 3.400 | 0.126 | 0.130 | 0.134 |
| E1 | - | - | - | - | - | - |
| E2 | 2.350 | 2.450 | 2.550 | 0.093 | 0.096 | 0.100 |
| e | 0.650 TYP | | | 0.026 | | |
| H | 0.35 | 0.450 | 0.550 | 0.014 | 0.018 | 0.022 |
| L | 0.35 | 0.450 | 0.550 | 0.014 | 0.018 | 0.022 |
| L1 | - | - | - | - | - | - |
| θ | - | - | - | - | - | - |

Recommended PCB Land Pattern



For recommended circuit layout for PCB designs, see application note [SLPA005 – Reducing Ringing Through PCB Layout Techniques](#).

Q3 Tape and Reel Information



Notes:

1. 10 sprocket hole pitch cumulative tolerance ± 0.2
2. Camber not to exceed 1mm IN 100mm, noncumulative over 250mm
3. Material: black static dissipative polystyrene
4. All dimensions are in mm (unless otherwise specified)
5. Thickness: 0.30 ± 0.05 mm
6. MSL1 260°C (IR and Convection) PbF Reflow Compatible

[查询 CSD16409Q3 供货情况](#)

REVISION HISTORY

Changes from Original (August 2009) to Revision A **Page**

-
- Deleted the Package Marking Information section [7](#)
-



www.ti.com

PACKAG

PACKAGING INFORMATION

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/ Ball Finish | MSL Peak Temp |
|------------------|-----------------------|--------------|-----------------|------|-------------|-------------------------|-------------------|---------------|
| CSD16409Q3 | ACTIVE | SON | DQG | 8 | 2500 | Pb-Free (RoHS Exempt) | CU SN | Level-1-260C |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSELETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com> for more information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all RoHS materials, with the exception of lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in applications that require high temperature soldering processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based eutectic solder used between the leadframe and die. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (unless otherwise designated in homogeneous material).

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI disclaims any warranty, expressed or implied, for the information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on all materials and is not responsible for any issues that arise from such testing or analysis. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

| Products | | Applications | |
|-----------------------------|--|----------------------------|--|
| Amplifiers | amplifier.ti.com | Audio | www.ti.com/audio |
| Data Converters | dataconverter.ti.com | Automotive | www.ti.com/automotive |
| DLP® Products | www.dlp.com | Communications and Telecom | www.ti.com/communications |
| DSP | dsp.ti.com | Computers and Peripherals | www.ti.com/computers |
| Clocks and Timers | www.ti.com/clocks | Consumer Electronics | www.ti.com/consumer-apps |
| Interface | interface.ti.com | Energy | www.ti.com/energy |
| Logic | logic.ti.com | Industrial | www.ti.com/industrial |
| Power Mgmt | power.ti.com | Medical | www.ti.com/medical |
| Microcontrollers | microcontroller.ti.com | Security | www.ti.com/security |
| RFID | www.ti-rfid.com | Space, Avionics & Defense | www.ti.com/space-avionics-defense |
| RF/IF and ZigBee® Solutions | www.ti.com/lprf | Video and Imaging | www.ti.com/video |
| | | Wireless | www.ti.com/wireless-apps |